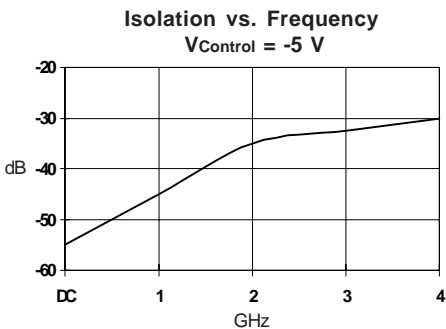


Product Description

Stanford Microdevices' SSW-508 is a high performance Gallium Arsenide Field Effect Transistor MMIC switch housed in a low-cost surface-mountable 8-pin small outline plastic package.

This single-pole, single-throw, non-reflective switch consumes less than 50uA and operates at -5V and 0V for control bias. P_{1dB} at -5V is +25dBm typical and can be increased to +28dBm with -8V supply.

The die is fabricated using 0.5 micron FET process with gold metallization and silicon nitride passivation to achieve excellent performance and reliability.



SSW-508

DC-4 GHz GaAs MMIC SPST Switch



Product Features

- High Isolation : 40dB at 1GHz, 30dB at 2GHz
- Low DC Power Consumption
- Low Insertion Loss : 1.0dB at 2GHz
- Non-Reflective
- Low Cost Small Outline Plastic Package

Applications

- Analog/Digital Wireless Communications
- AMPS, PCS, DEC and GSM Bands

Electrical Specifications at Ta = 25C

Symbol	Parameters & Test Conditions: Z ₀ = 50 ohms V = -5 V		Units	Min.	Typ.	Max.
Ins.	Insertion Loss	f = 0.05-1.0 GHz	dB		0.8	1.2
		f = 1.00-2.0 GHz	dB		1.0	1.4
		f = 2.00-4.0 GHz	dB		1.2	
Isol.	Isolation	f = 0.05-1.0 GHz	dB	35	45	
		f = 1.00-2.0 GHz	dB	25	35	
		f = 2.00-4.0 GHz	dB		30	
VSW Ron	Input & Output VSWR (on or low loss state)	f = 0.05-2.0 GHz	-		1.3	
		f = 2.00-4.0 GHz	-		1.7	
VSW Roff	Input & Output VSWR (off or isolated state)	f = 0.05-2.0 GHz	-		1.3	
		f = 2.00-4.0 GHz	-		1.7	
P _{1dB}	1dB Compression at 2.0 GHz	V = -5V	dBm		+25	
		V = -8V	dBm		+28	
TOIP	Third Order Intercept Point	V = -5V	dBm		+44	
		V = -8V	dBm		+47	
ID	Device Current		uA		40	
Isw	Switching Speed 10% to 90% or 90% to 10%		nS		10	

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SSW-508 DC-4 GHz GaAs MMIC SPST Switch

Absolute Maximum Ratings

RF Input Power	2W Max>500MHz
Device Voltage	-10V
Operating Temperature	-45C to +85C
Storage Temperature	-65C to +150C
Thermal Resistance	20 deg C/W

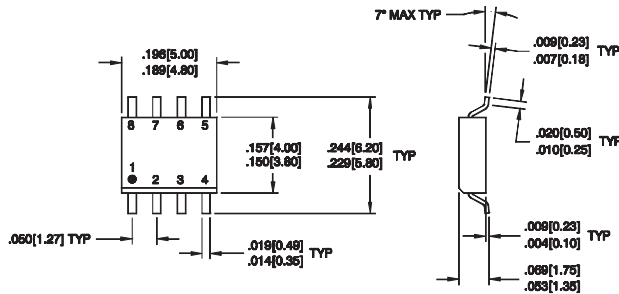
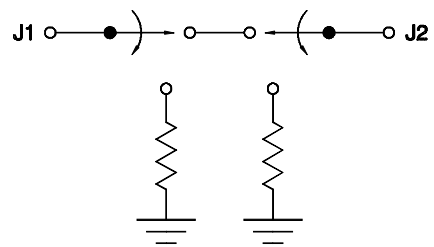
Truth Table

V1	V2	J1-J2	J1-J3
-5	0	Low Loss	Isolation
0	-5	Isolation	Low Loss

Pin Out

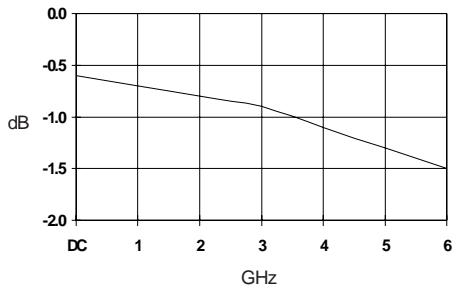
Pin	Function
1	J1
2	V1
3	V2
4	GND
5	J2
6	GND
7	GND
8	GND

Switch Schematic



Pin numbers shown for reference only, not marked on part

Insertion Loss vs. Frequency V_{Control} = -5 V



On Port Input/Output VSWR vs. Frequency V_{Control} = -5 V

